

1775,515.

PATENTS

IN THE UNITED STATES PATENT AND TRADEMARK OFFICE

Applicant:

J.O. Chu, et al.

Docket: 16315A

Patent No.: 6,908,866

Dated: August 03, 2005

Issued: June 21, 2005

For: EPITAXIAL AND POLYCRYSTALLINE

GROWTH OF SI_{1-x-v}GE_xC_v AND SI_{1-v}C_v

ALLOY LAYERS ON SI BY UHV-CVD

Certificate AUG 1 5 2005

of Correction

Commissioner for Patents P.O. Box 1450 Alexandria, VA 22313-1450

REQUEST FOR CERTIFICATE OF CORRECTION

Sir:

It appears that errors have been introduced in the course of printing the Patent issued in the above application, and it is respectfully requested that the Commissioner issue a Certificate of Correction in the following respects:

(75)<u>Inventors</u>

"Basanth Jagannathan, Stormville, NY (US);"

should read

-- Basanth Jagannathan, Beacon, NY (US) --

Column 3, Line 30:

"very thin epitanal layers" should read -- very thin epitaxial layers --

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Please replace TABLE 1 appearing at Column 11, Line 19 through 34, with the following TABLE 1 which is printed accordance to the originally filed table.

TABLE 1

Dete	LC10 P1	T . C	T. C	1 0/ 3
1/00	C and O Baselines	Interface C/cm ²	Interface O/cm ²	C/cm ³
	for Hex Tool 349,	C/cm	O/cm	In epi
	Mostly March-May 2000			
	Referenced to			
	standard "11" which			
	•			
	is similar to YKT			
	3/00 C/O PR952-12	3.9E12	1.9E12	1.1E17
	Run21431E72-UMC	3.9E12	1.9E12	1.161/
	A Ruii21431E/2-UNIC	-		
	revisit			
3/02	CP1057-Run247	2.7E12	6.0E11	
	UHVA	2./E12	0.0E11	
3/02	CP1057-Run255	2.6E12	1.9E12	1.1E17
	SSDA SSDA	2.0E12	1.9612	1.1617
3/02	CP1057-Run258	5.5E12	1.1E13	1.4E17
3/02	CP1057-Run262	1.4E13	2.4E13	1.4E17
	SSOA			
3/31/00	CP1126 Run302	6.0E12	1.1E13	1.5E17
	Slot5 After			
	Recovery			
3/31/00	CP1126 Run302	6.0E12	706E12	1.5E17
	Slot after recovery			
4/4	CP1135 Run310	3.0E12	1.3E12	1.1E17
	Slot8 FILTER IN			
	PLACE, ethylene			
	run			
4/24	CP1178-2 Run 324	3E12	4E12	1.0E17
	After ethylene runs	-		
5/2	CP1197-Run333	5.4E12	1.2E13	1.5E17
	Control Run After			
	ethylene			
5/14	CP1232 run after	5.4E12	9E12	1.2E17
	Ethylene runs			
6/8	CP 1314 - Run 376	1e13	1.2e13	1.4e17
	after			
	ethylene run			
	CP-1314 Run 378?	1.5E13	1.9E13	1.4E17
6/15	CP 13124 – Run	1.4E13	2.0E13	1.3E17
	380 after the			
	ethylene run			

Consideration and entry of the above corrections are respectfully requested.

Respectfully submitted,

Leslie S. Szivos

Reg. No. 39,394

Scully, Scott, Murphy & Presser 400 Garden City Plaza, Suite 300 Garden City, New York 11530 (516) 742-4343 LSS/al

UNITED STATES PATENT AND TRADEMARK OFFICE **CERTIFICATE OF CORRECTION**

PATENT NO

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6,908,866

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APPLICATION NO: 10/775,515

ISSUE DATE

: June 21, 2005

INVENTOR(S)

: J.O. Chu, et al.

It is certified that an error appears or errors appear in the above-identified patent and that said Letters Patent is hereby corrected as shown below:

(75) Inventors

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should read

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MAILING ADDRESS OF SENDER:

PATENT NO. 6,908,866

Scully, Scott, Murphy & Presser 400 Garden City Plaza, Suite 300 Garden City, New York 11530

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